- 150-mA Load Current Without External Power Transistor
- Typically 0.02% Input Regulation and 0.03% Load Regulation (μΑ723M)
- Adjustable Current-Limiting Capability
- Input Voltages to 40 V
- Output Adjustable From 2 V to 37 V
- Direct Replacement for Fairchild μA723C and μA723M

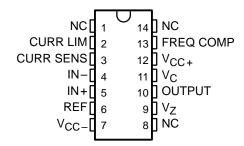
description

The μ A723C and μ A723M are precision monolithic integrated circuit voltage regulators featuring high ripple rejection, excellent input and load regulation, excellent temperature stability, and low standby current. The circuit consists of a temperature-compensated reference-voltage amplifier, an error amplifier, a 150-mA output transistor, and an adjustable output current limiter.

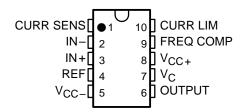
The μ A723C and μ A723M are designed for use in positive or negative power supplies as a series, shunt, switching, or floating regulator. For output currents exceeding 150 mA, additional pass elements may be connected as shown in Figures 4 and 5.

The μ A723C is characterized for operation from 0°C to 70°C. The μ A723M is characterized for operation over the full military temperature range of -55°C to 125°C.

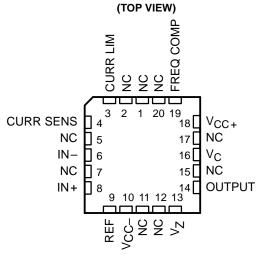
μΑ723C ... D OR N PACKAGE μΑ723M ... J PACKAGE (TOP VIEW)



μΑ723M . . . U PACKAGE (TOP VIEW)



$\mu \text{A723M} \dots \text{FK PACKAGE}$



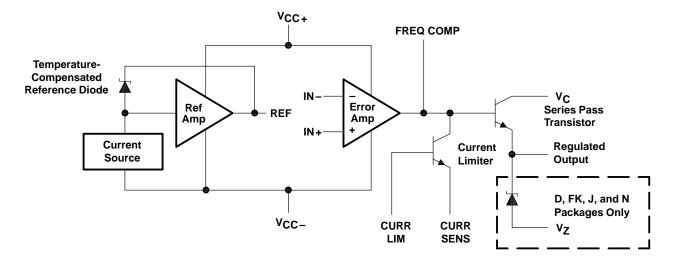
NC - No internal connection



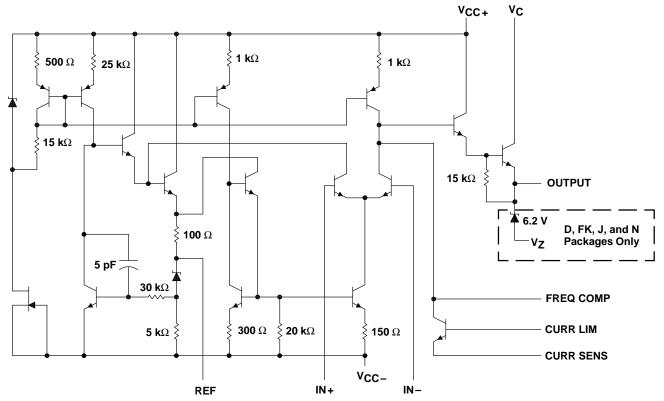
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functional block diagram



schematic



Resistor and capacitor values shown are nominal.



μΑ723Y chip information

This chip, when properly assembled, displays characteristics similar to the μ A723C. Thermal compression or ultrasonic bonding can be used on the doped aluminum bonding pads. The chips can be mounted with conductive epoxy or a gold-silicon preform.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Peak voltage from V_{CC+} to V_{CC-} ($t_w \le 50$ ms)	50 V
Continuous voltage from V _{CC+} to V _{CC-}	40 V
Input-to-output voltage differential	40 V
Differential input voltage to error amplifier	±5 V
Voltage between noninverting input and V _{CC}	8 V
Current from V _Z	25 mA
Current from REF	15 mA
Continuous total dissipation (see Note 1)	See Dissipation Rating Table
Operating free-air temperature range, T _A : μA723C	0°C to 70°C
μA723M	
Storage temperature range, T _{stq}	65°C to 150°C
Case temperature for 60 seconds, T _C : FK package	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or U packa	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Power dissipation = $[I_{(standby)} + I_{(ref)}] V_{CC} + [V_C - V_O] I_O$.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	950 mW	7.6 mW/°C	25°C	608 mW	
FK and J	1000 mW	11.0 mW/°C	59°C	879 mW	274 mW
N	1000 mW	9.2 mW/°C	41°C	733 mW	_
U	675 mW	5.4 mW/°C	25°C	432 mW	135 mW

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V _I	9.5	40	V
Output voltage, VO	2	37	V
Input-to-output voltage differential, V _C – V _O	3	38	V
Output current, IO		150	mA



electrical characteristics at specified free-air temperature (see Notes 2 and 3)

DADAMETED	TEST CONDITION	TEST CONDITIONS	T _A †	μ Α723C		μ Α723M			UNIT		
PARAMETER	1EST CONDITIO	TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNII	
	$V_{ } = 12 \text{ V to } V_{ } = 15 \text{ V}$		25°C		0.1	1		0.1	1		
Input regulation	$V_{ } = 12 \text{ V to } V_{ } = 40 \text{ V}$		25°C		1	5		0.2	2	mV/V	
input regulation	V _I = 12 V to V _I = 15 V		Full range			3			3	111070	
Dipple rejection	$f = 50 H_Z \text{ to } 10 \text{ kHz},$	$C_{ref} = 0$	25°C		74			74		dB	
Ripple rejection	f = 50 Hz to 10 kHz,	$C_{ref} = 5 \mu F$	25°C		86			86		uБ	
			25°C		-0.3	-2		-0.3	-1.5		
Output regulation			Full			-6			-6	mV/V	
			range								
Reference voltage, Vref			25°C	6.8	7.15	7.5	6.95	7.15	7.35	V	
Standby current	V _I = 30 V,	I _O = 0	25°C		2.3	4		2.3	3.5	mA	
Temperature coefficient of output voltage			Full range		0.003	0.015		0.002	0.015*	%/°C	
Short-circuit output current	$R_{SC} = 10 \Omega$,	V _O = 0	25°C		65			65		mA	
Output maios valtams	BW = 100 Hz to 10 kHz,	$C_{ref} = 0$	25°C		20			20			
Output noise voltage	BW = 100 Hz to 10 kHz,	C _{ref} = 5 μF	25°C		2.5			2.5		μV	

^{*}On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

electrical characteristics, T_A = 25°C (see Notes 2 and 3)

PARAMETER	TEST CONDITIONS			μ Α723Y			
PARAMETER				TYP	MAX	UNIT	
Input regulation	$V_{ } = 12 \text{ V to } V_{ } = 15 \text{ V}$		0.1			mV/V	
Input regulation	$V_{\parallel} = 12 \text{ V to } V_{\parallel} = 40 \text{ V}$			1			
Ripple rejection	$f = 50 H_Z$ to 10 kHz,	$C_{ref} = 0$	74			dB	
Rippie rejection	f = 50 Hz to 10 kHz,	$C_{ref} = 5 \mu F$		86		uБ	
Output regulation				-0.3		mV/V	
Reference voltage, V _{ref}				7.15		V	
Standby current	V _I = 30 V,	I _O = 0		2.3		mA	
Short-circuit output current	$R_{SC} = 10 \Omega$	V _O = 0		65		mA	
Output noise voltage	BW = 100 Hz to 10 kHz,	$C_{ref} = 0$		20		μV	
Output noise voitage	BW = 100 Hz to 10 kHz,	$C_{ref} = 5 \mu F$		2.5	·	μν	

NOTES: 2. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier \leq 10 kΩ. Unless otherwise specified, $V_I = V_{CC+} = V_C = 12 \text{ V}$, $V_{CC-} = 0$, $V_O = 5 \text{ V}$, $I_O = 1 \text{ mA}$, $R_{SC} = 0$, and $C_{ref} = 0$.

3. Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.



[†] Full range for μ A723C is 0°C to 70°C and for μ A723M is -55°C to 125°C.

NOTES: 2. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier \leq 10 k Ω . Unless otherwise specified, $V_I = V_{CC+} = V_C = 12$ V, $V_{CC-} = 0$, $V_O = 5$ V, $V_{CC-} = 0$, and $V_{CC-} = 0$.

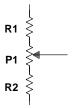
^{3.} Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

Table 1. Resistor Values ($k\Omega$) for Standard Output Voltages

OUTPUT VOLTAGE	APPLICABLE FIGURES	FIXED OUTPUT ±5%		OUTPUT ADJUSTABLE ±10% (see NOTE 5)			
(V)	(see NOTE 4)	R1 (kΩ)	R2 (kΩ)	R1 (kΩ)	P1 (kΩ)	P2 (kΩ)	
3.0	1, 5, 6, 9, 11, 12 (4)	4.12	3.01	1.8	0.5	1.2	
3.6	1, 5, 6, 9, 11, 12 (4)	3.57	3.65	1.5	0.5	1.5	
5.0	1, 5, 6, 9, 11, 12 (4)	2.15	4.99	0.75	0.5	2.2	
6.0	1, 5, 6, 9, 11, 12 (4)	1.15	6.04	0.5	0.5	2.7	
9.0	2, 4, (5, 6, 9, 12)	1.87	7.15	0.75	1.0	2.7	
12	2, 4, (5, 6, 9, 12)	4.87	7.15	2.0	1.0	3.0	
15	2, 4, (5, 6, 9, 12)	7.87	7.15	3.3	1.0	3.0	
28	2, 4, (5, 6, 9, 12)	21.0	7.15	5.6	1.0	2.0	
45	7	3.57	48.7	2.2	10	39	
75	7	3.57	78.7	2.2	10	68	
100	7	3.57	105	2.2	10	91	
250	7	3.57	255	2.2	10	240	
-6 (see Note 6)	3, 10	3.57	2.43	1.2	0.5	0.75	
-9	3, 10	3.48	5.36	1.2	0.5	2.0	
-12	3, 10	3.57	8.45	1.2	0.5	3.3	
-15	3, 10	3.57	11.5	1.2	0.5	4.3	
-28	3, 10	3.57	24.3	1.2	0.5	10	
-45	8	3.57	41.2	2.2	10	33	
-100	8	3.57	95.3	2.2	10	91	
-250	8	3.57	249	2.2	10	240	

NOTES: 4. The R1/R2 divider may be across either V_O or V_(ref). If the divider is across V_(ref), use the figure numbers without parentheses. If the divider is across V_O, use the figure numbers in parentheses.

5. To make the voltage adjustable, the R1/R2 divider shown in the figures must be replaced by the divider shown below.



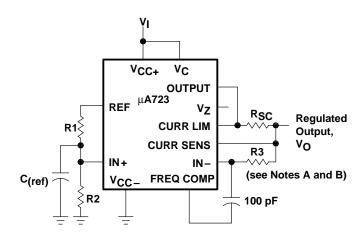
Adjustable Output Circuit

6. For Figures 3, 8, and 10, the device requires a minimum of 9 V between V_{CC+} and V_{CC-} when V_{O} is equal to or more positive than -9 V.

Table 2. Formulas for Intermediate Output Voltages

Outputs from 2 V to 7 V See Figures 1, 5, 6, 9, 11, 12 (4) and Note 4	Outputs from 4 V to 250 V See Figure 7 and Note 4	Current Limiting
$V_{O} = V_{(ref)} \times \frac{R2}{R1 + R2}$	$V_O = \frac{V(ref)}{2} \times \frac{R2-R1}{R1}$	$I_{\text{(limit)}} \approx \frac{0.65 \text{ V}}{R_{\text{SC}}}$
	R3 = R4	
Outputs from 7 V to 37 V See Figures 2, 4, (5, 6, 9, 11, 12) and Note 4	Outputs from -6 V to -250 V See Figures 3, 8, 10 and Notes 4 and 6	Foldback Current Limiting See Figure 6
$V_O = V_{(ref)} \times \frac{R1 + R2}{R2}$	$V_O = -\frac{V(ref)}{2} \times \frac{R1 + R2}{R1}$	$I_{\text{(knee)}} \approx \frac{V_{\text{O}}R3 + (R3 + R4) \ 0.65 \ V}{R_{\text{SC}}R4}$
	R3 = R4	$I_{OS} \approx \frac{0.65 \text{ V}}{R_{SC}} \times \frac{R3 + R4}{R4}$

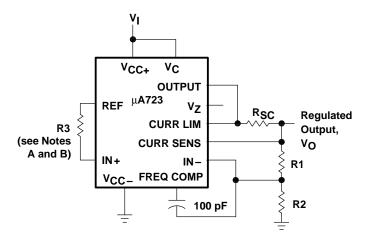
- NOTES: 4. The R1/R2 divider can be across either V_O or $V_{(ref)}$. If the divider is across $V_{(ref)}$, use figure numbers without parentheses. If the divider is across V_O , use the figure numbers in parentheses.
 - 6. For Figures 3, 8, and 10, the device requires a minimum of 9 V between V_{CC+} and V_{CC-} when V_O is equal to or more positive than -9 V.



NOTES: A. R3 = $\frac{R1 \times R2}{R1 + R2}$ for minimum α_{VO}

B. R3 may be eliminated for minimum component count. Use direct connection (i.e., $R_3 = 0$).

Figure 1. Basic Low-Voltage Regulator $(V_O = 2 \text{ V to 7 V})$



NOTES: A. R3 = $\frac{R1 \times R2}{R1 + R2}$ for minimum $\alpha_{\mbox{VO}}$

B. R3 may be eliminated for minimum component count. Use direct connection (i.e., $R_3 = 0$).

Figure 2. Basic High-Voltage Regulator (V_O = 7 V to 37 V)

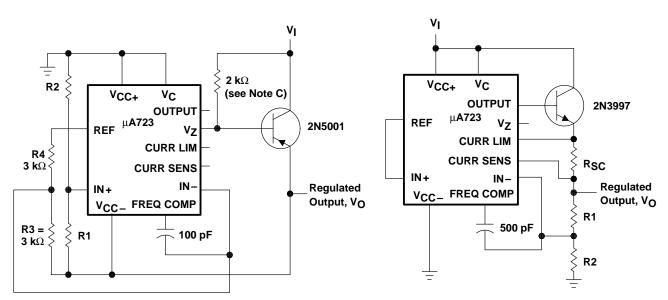


Figure 3. Negative-Voltage Regulator

Figure 4. Positive-Voltage Regulator (External N-P-N Pass Terminator)

NOTE A: When 10-lead µA723U devices are used in applications requiring V_Z, an external 6.2-V regulator diode must be connected in series with OUTPUT.



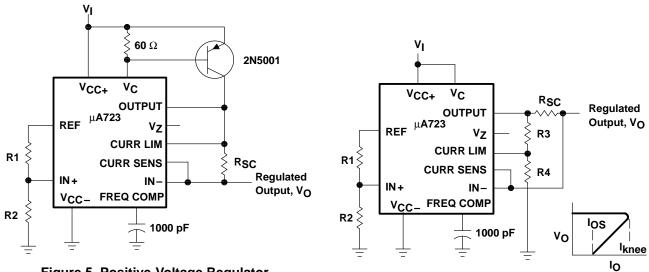
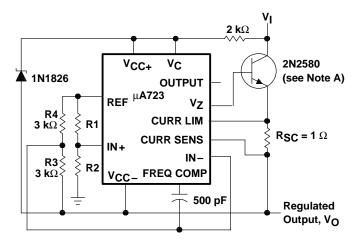


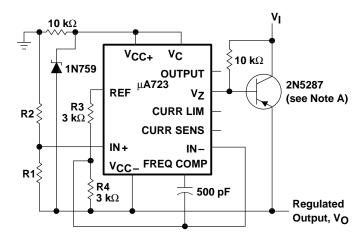
Figure 5. Positive-Voltage Regulator (External P-N-P Pass Transistor)

Figure 6. Foldback Current Limiting



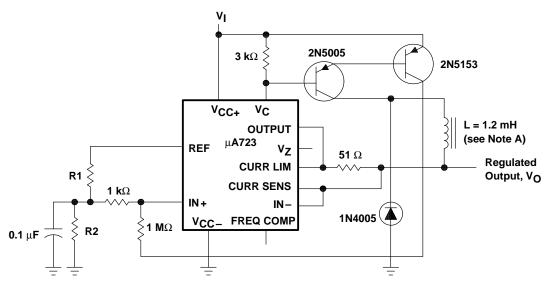
NOTE A: When 10-lead μ A723U devices are used in applications requiring V_Z, an external 6.2-V regulator diode must be connected in series with OUTPUT.

Figure 7. Positive Floating Regulator



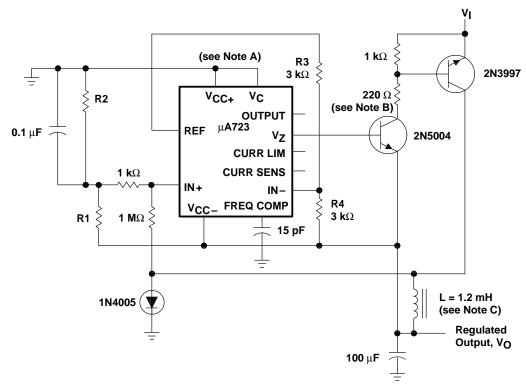
NOTE A: When 10-lead $\mu A723U$ devices are used in applications requiring Vz, an external 6.2-V regulator diode must be connected in series with OUTPUT.

Figure 8. Negative Floating Regulator



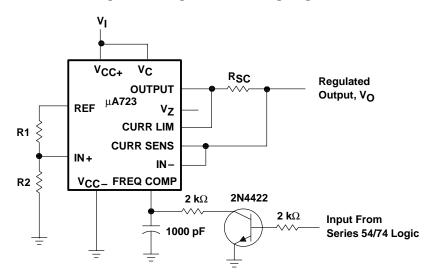
NOTE A: L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core or equivalent, with a 0.009-inch air gap.

Figure 9. Positive Switching Regulator



- NOTES: A. The device requires a minimum of 9 V between V_{CC+} and V_{CC-} when V_O is equal to or more positive than -9 V.
 - B. When 10-lead µA723U devices are used in applications requiring V_Z, an external 6.2-V regulator diode must be connected in series with OUTPUT.
 - C. L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core or equivalent, with a 0.009-inch air gap.

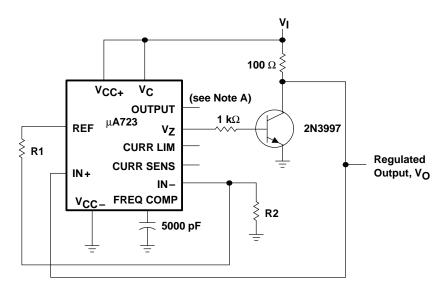
Figure 10. Negative Switching Regulator



NOTE A: A current-limiting transistor can be used for shutdown if current limiting is not required.

Figure 11. Remote Shutdown Regulator With Current Limiting





NOTE A: When 10-lead μ A723U devices are used in applications requiring V_Z, an external 6.2-V regulator diode must be connected in series with OUTPUT.

Figure 12. Shunt Regulator



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